

Q3-Class HiperFET[™] Power MOSFET

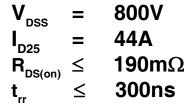
IXFK44N80Q3 IXFX44N80Q3

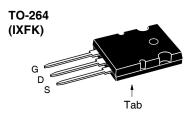
N-Channel Enhancement Mode Avalanche Rated Fast Intrinsic Rectifier

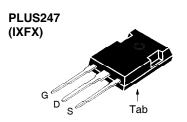


Symbol	Test Conditions	Maximum	Ratings
V _{DSS}	T _J = 25°C to 150°C	800	V
V _{DGR}	$T_{_{\rm J}} = 25^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}, R_{_{\rm GS}} = 1\text{M}\Omega$	800	V
V _{GSS}	Continuous	±30	V
V _{GSM}	Transient	±40	V
I _{D25}	T _C = 25°C	44	A
I _{DM}	$T_{\rm C} = 25^{\circ}$ C, Pulse Width Limited by $T_{\rm JM}$	130	Α
I _A E _{AS}	T _c = 25°C T _c = 25°C	44 3.5	A J
dv/dt	$I_{_{S}} \le I_{_{DM}}, V_{_{DD}} \le V_{_{DSS}}, T_{_{J}} \le 150^{\circ}C$	50	V/ns
P_{D}	T _c = 25°C	1250	W
T _J T _{JM} T _{stg}		-55 +150 150 -55 +150	°C °C °C
T _L T _{SOLD}	Maximum Lead Temperature for Soldering Plastic Body for 10s	300 260	°C °C
M _d F _c	Mounting Torque (TO-264) Mounting Force (PLUS247)	1.13/10 20120 /4.527	Nm/lb.in. N/lb.
Weight	TO-264 PLUS247	10 6	g g

Symbol (T _J = 25°C	Test Conditions Unless Otherwise Specified)	Chara Min.	cteristic Typ.	Values Max	
BV _{DSS}	$V_{GS} = 0V, I_D = 3mA$	800			V
V _{GS(th)}	$V_{DS} = V_{GS}$, $I_{D} = 8mA$	3.5		6.5	V
I _{gss}	$V_{GS} = \pm 30V$, $V_{DS} = 0V$			±200	nA
I _{DSS}	$V_{DS} = V_{DSS}, V_{GS} = 0V$ $T_{J} = 12$	5°C		50 2.5	μA mA
R _{DS(on)}	$V_{GS} = 10V, I_{D} = 0.5 \bullet I_{D25}, \text{ Note 1}$			190	mΩ







G	=	Gate	D	=	Drain
S	=	Source	Tab) =	Drain

Features

- Avalanche Rated
- Low Intrinsic Gate Resistance
- Low Package Inductance
- Fast Intrinsic Rectifier
- Low $R_{DS(on)}$ and Q_g

Advantages

- High Power Density
- Easy to Mount
- Space Savings

Applications

- DC-DC Converters
- Battery Chargers
- Switch-Mode and Resonant-Mode Power Supplies
- DC Choppers
- Temperature and Lighting Controls



Symbol	Symbol Test Conditions Charac			cteristic Values		
$(T_J = 25)$	°C U	nless Otherwise Specified)	Min.	Тур.	Max.	
g _{fs}		$V_{DS} = 20V, I_{D} = 0.5 \bullet I_{D25}, \text{ Note 1}$	22	37	S	
C _{iss})			10950	pF	
C _{oss}	}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		957	pF	
C _{rss}	J			95	pF	
\mathbf{R}_{Gi}		Gate Input Resistance		0.20	Ω	
t _{d(on)})	Resistive Switching Times		45	ns	
t _r		$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		60	ns	
$\mathbf{t}_{d(off)}$				63	ns	
t _f)	$R_{g} = 1\Omega$ (External)		20	ns	
Q _{g(on)})			185	nC	
\mathbf{Q}_{gs}	}	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		67	nC	
\mathbf{Q}_{gd}	J			83	nC	
R _{thJC}					0.10 °C/W	
R _{thCS}				0.15	°C/W	

Source-Drain Diode

Symbol (T _J = 25°C U	Test Conditions Inless Otherwise Specified)	Chara Min.	cteristic Typ.	Values Max.	
I _s	$V_{GS} = 0V$			44	Α
I _{sm}	Repetitive, Pulse Width Limited by $T_{_{ m JM}}$			176	Α
V _{SD}	$I_F = I_S$, $V_{GS} = 0V$, Note 1			1.4	V
$\left\{ egin{array}{ll} \mathbf{t}_{rr} & \\ \mathbf{Q}_{RM} & \\ \mathbf{I}_{RM} & \end{array} ight\}$	$I_F = 22A$, -di/dt = 100A/ μ s $V_R = 100V$, $V_{GS} = 0V$		1.8 13.4	300	ns μC Α

Note 1. Pulse test, $t \le 300 \mu s$, duty cycle, $d \le 2\%$.



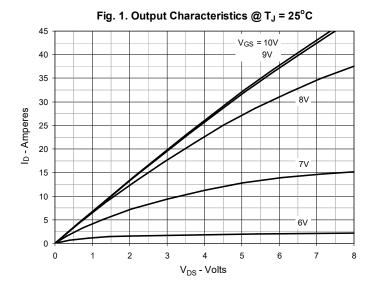
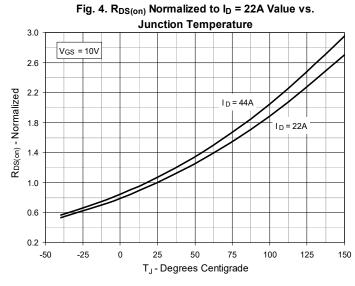
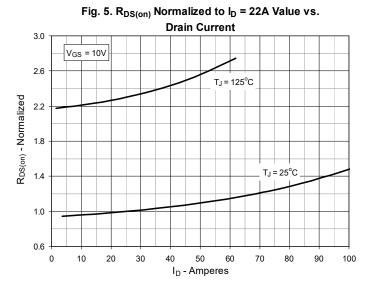
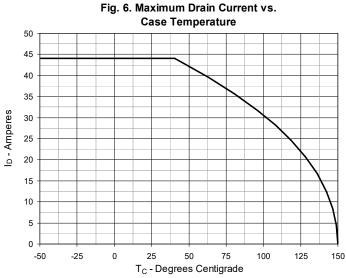


Fig. 2. Extended Output Characteristics @ T_J = 25°C Ip - Amperes 7V 6V V_{DS} - Volts

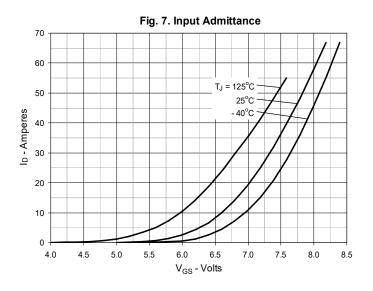
Fig. 3. Output Characteristics @ T_J = 125°C V_{GS} = 10V ID - Amperes 7V 6V V_{DS} - Volts

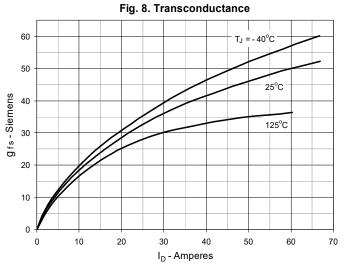


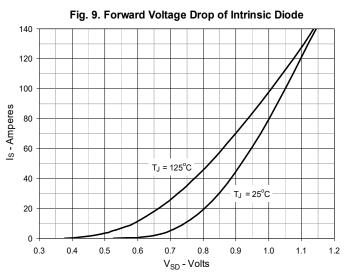


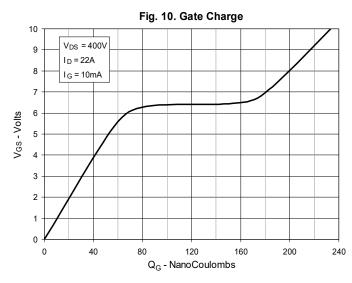


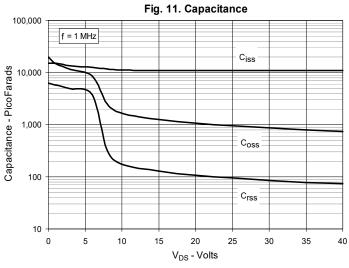


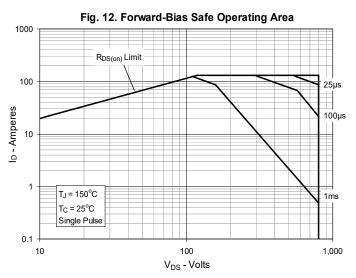












IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.



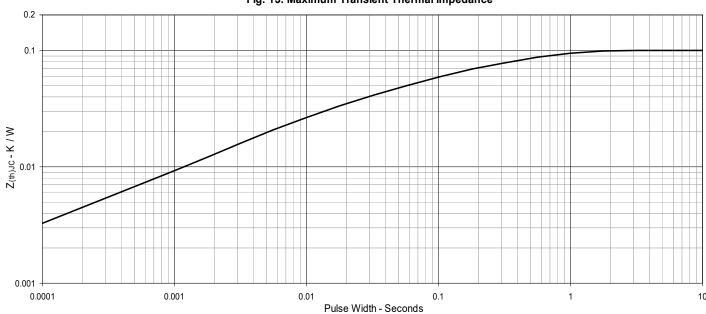
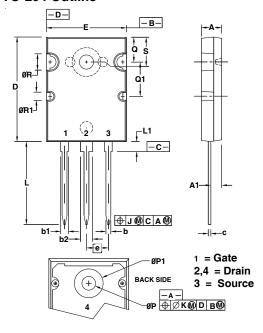


Fig. 13. Maximum Transient Thermal Impedance

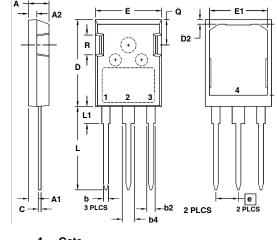


TO-264 Outline



CVMDOL	INCHES		MILLIMETERS	
SYMBOL	MIN	MAX	MIN	MAX
Α	.185	.209	4.70	5.31
A1	.102	.118	2.59	3.00
b	.037	.055	0.94	1.40
b1	.087	.102	2.21	2.59
b2	.110	.126	2.79	3.20
С	.017	.029	0.43	0.74
D	1.007	1.047	25.58	26.59
E	.760	.799	19.30	20.29
е	.215	BSC	5.46	BSC
J	.000	.010	0.00	0.25
K	.000	.010	0.00	0.25
L	.779	.842	19.79	21.39
L1	.087	.102	2.21	2.59
ØΡ	.122	.138	3.10	3.51
øP1	.270	.290	6.86	7.37
Q	.240	.256	6.10	6.50
Q1	.330	.346	8.38	8.79
ØR	.155	.187	3.94	4.75
øR1	.085	.093	2.16	2.36
S	.243	.253	6.17	6.43

PLUS247™ Outline



	<u> [</u>	2 3		-
A1	L1 t		2 PLCS	e 2 PLCS
1 = G 2,4 = 3 = S	Drain			

SYM	INCH	INCHES		MILLIMETERS	
SIM	MIN	MAX	MIN	MAX	
Α	190،	.205	4.83	5.21	
Α1	.090	.100	2.29	2.54	
A2	.075	.085	1.91	2.16	
b	.045	.055	1.14	1,40	
b2	.075	.087	1.91	2,20	
b4	.115	.126	2.92	3,20	
С	.024	،031	0.61	0,80	
D	.819	.840	20.80	21.34	
D1	.650	.690	16.51	17.53	
D2	.035	.050	0.89	1.27	
E	.620	.635	15.75	16.13	
E1	.520	.560	13.08	14.22	
е	.215	BSC	5.45	BSC	
L	.780	.810	19,81	20.57	
L1	.150	.170	3.81	4.32	
Q	.220	.244	5.59	6.20	
R	.170	.190	4.32	4.83	





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